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Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

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Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





FW813 — N-Channel Silicon MOSFET

General-Purpose Switching Device

Applications

Features

- ON-resistance $R_{DS(on)} = 39m\Omega$ (typ.)
- 4V drive
- Nch + Nch MOSFET

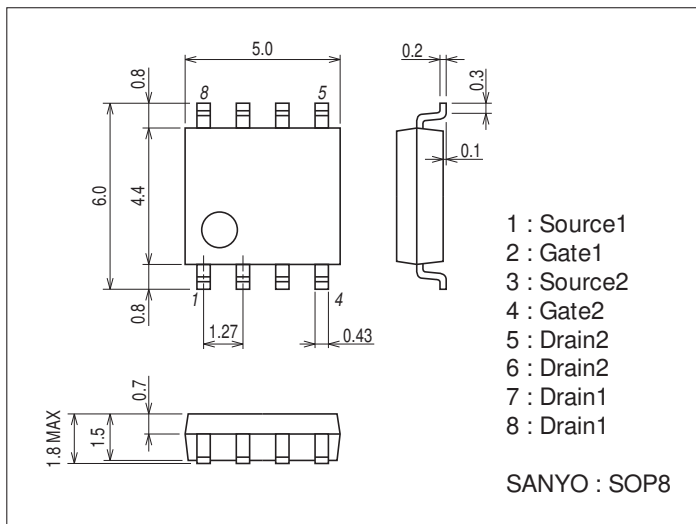
Specifications

Absolute Maximum Ratings at $T_a = 25^\circ C$

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V_{DSS}		60	V
Gate-to-Source Voltage	V_{GSS}		± 20	V
Drain Current (DC)	I_D		5	A
Drain Current (Pulse)	I_{DP}	$PW \leq 10\mu s$, duty cycle $\leq 1\%$	52	A
Allowable Power Dissipation	P_D	When mounted on ceramic substrate (2000mm ² × 0.8mm) 1unit, $PW \leq 10s$	2.3	W
Total Dissipation	P_T	When mounted on ceramic substrate (2000mm ² × 0.8mm), $PW \leq 10s$	2.5	W
Channel Temperature	T_{ch}		150	$^\circ C$
Storage Temperature	T_{stg}		-55 to +150	$^\circ C$

Package Dimensions

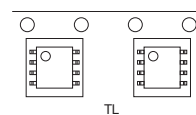
unit : mm (typ)
7005A-003



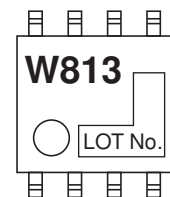
Product & Package Information

- Package : SOP8
- JEITA, JEDEC : SC-87, SOT96
- Minimum Packing Quantity : 1,000 pcs./reel

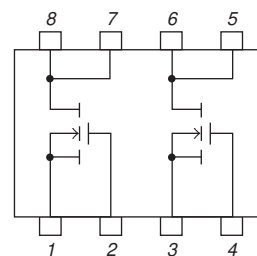
Packing Type : TL



Marking



Electrical Connection

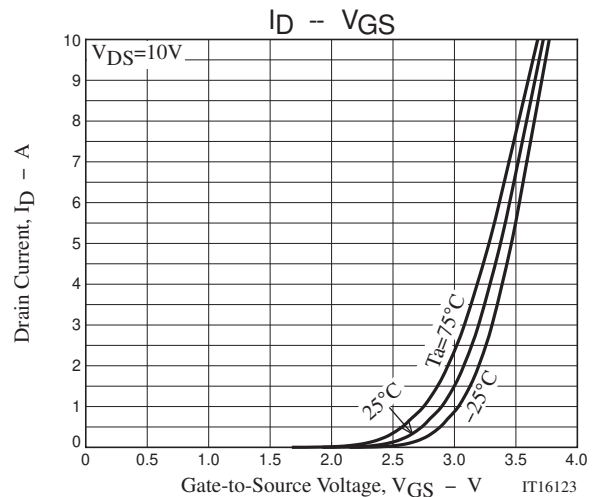
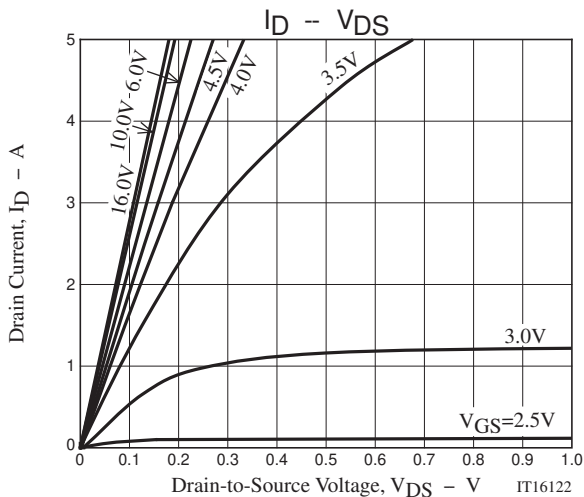
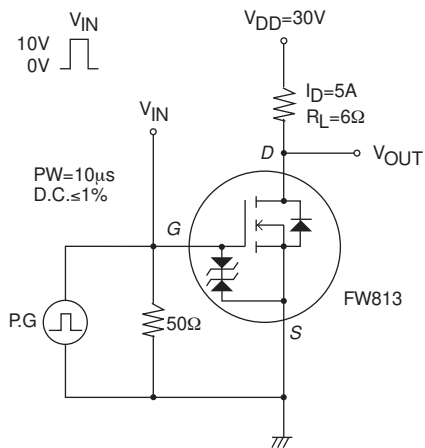


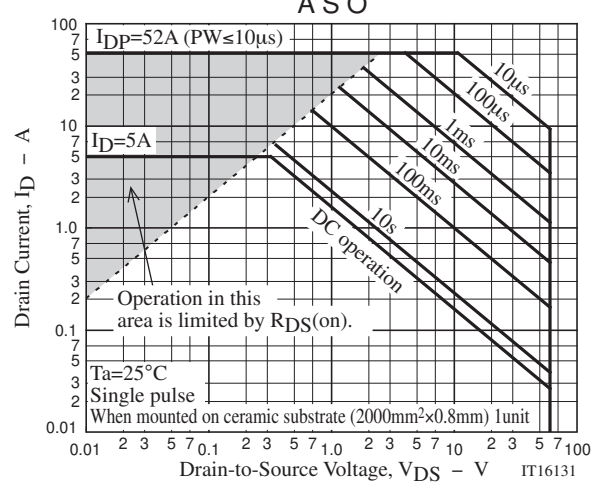
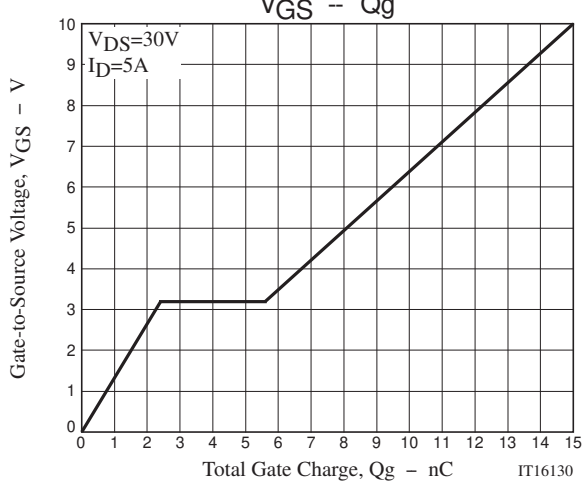
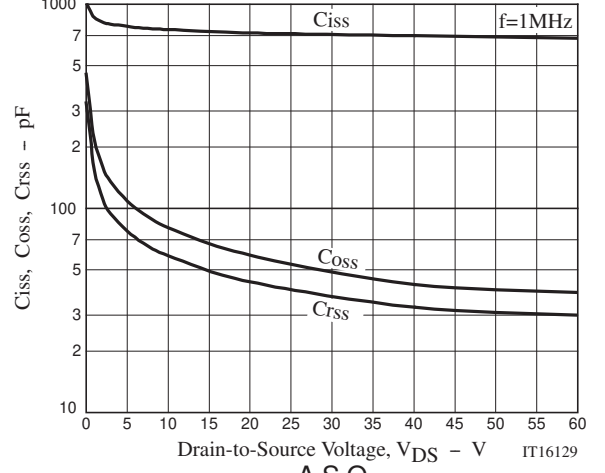
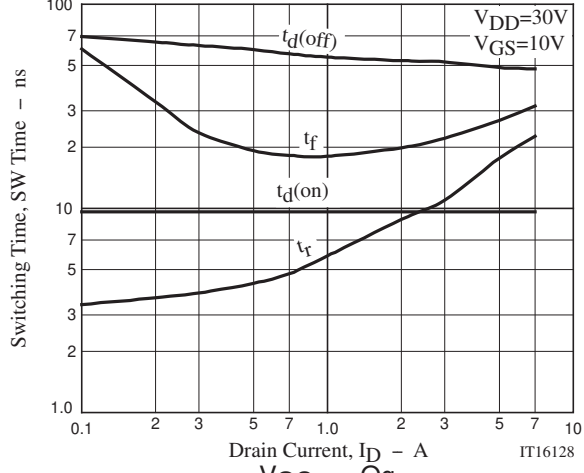
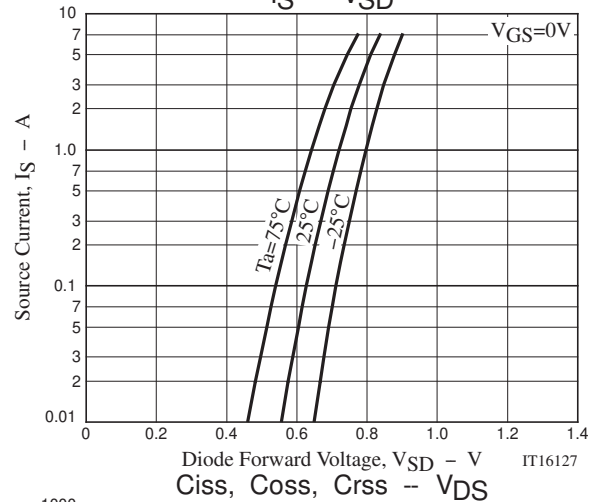
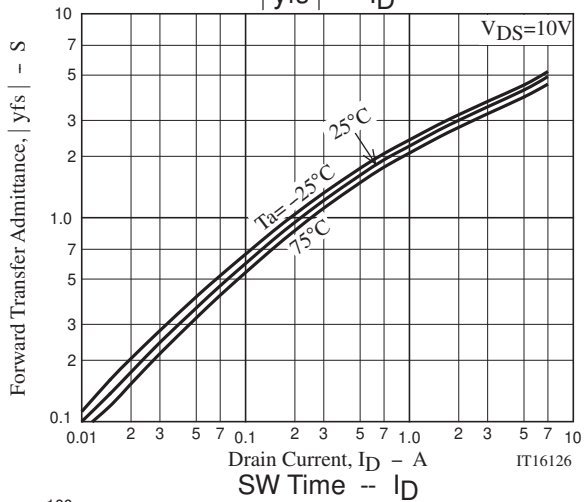
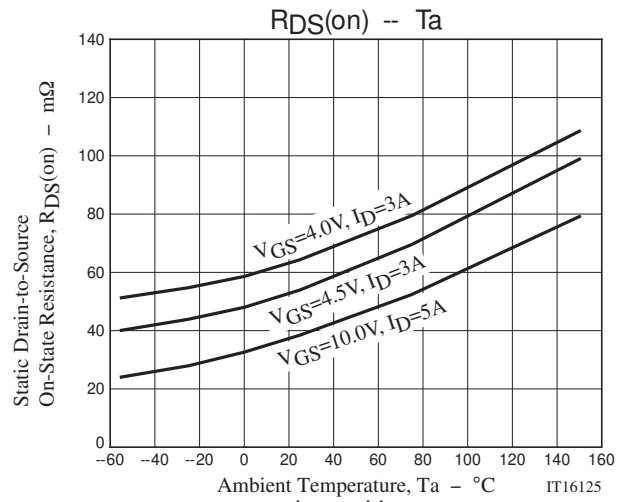
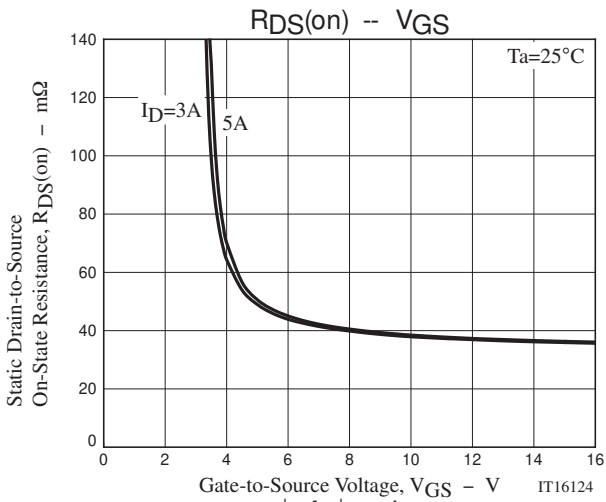
FW813

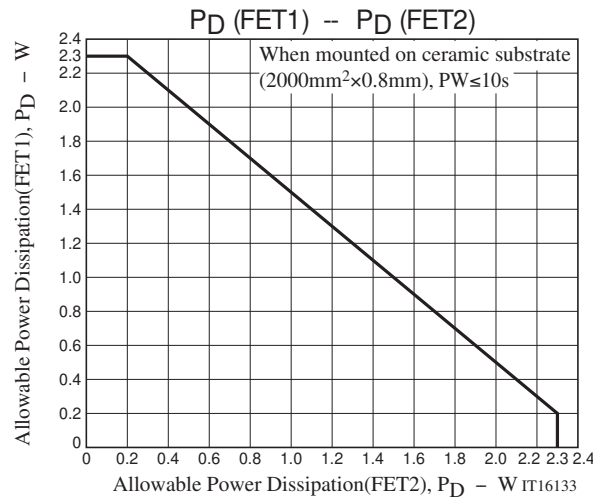
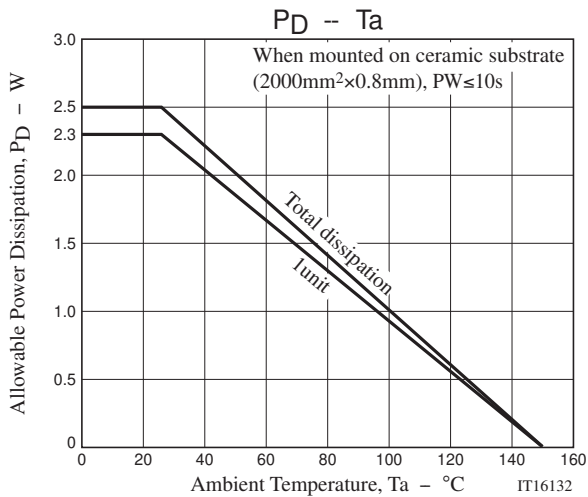
Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D=1mA, V_{GS}=0V$	60			V
Zero-Gate Voltage Drain Current	I_{DSS}	$V_{DS}=60V, V_{GS}=0V$			1	μA
Gate-to-Source Leakage Current	I_{GSS}	$V_{GS}=\pm 16V, V_{DS}=0V$			± 10	μA
Cutoff Voltage	$V_{GS(off)}$	$V_{DS}=10V, I_D=1mA$	1.2		2.6	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS}=10V, I_D=5A$		4.2		S
Static Drain-to-Source On-State Resistance	$R_{DS(on)1}$	$I_D=5A, V_{GS}=10V$		39	49	$m\Omega$
	$R_{DS(on)2}$	$I_D=3A, V_{GS}=4.5V$		54	76	$m\Omega$
	$R_{DS(on)3}$	$I_D=3A, V_{GS}=4V$		64	90	$m\Omega$
Input Capacitance	C_{iss}	$V_{DS}=20V, f=1MHz$		725		pF
Output Capacitance	C_{oss}	$V_{DS}=20V, f=1MHz$		60		pF
Reverse Transfer Capacitance	C_{rss}	$V_{DS}=20V, f=1MHz$		45		pF
Turn-ON Delay Time	$t_{d(on)}$	See specified Test Circuit.		9.6		ns
Rise Time	t_r	See specified Test Circuit.		18		ns
Turn-OFF Delay Time	$t_{d(off)}$	See specified Test Circuit.		49		ns
Fall Time	t_f	See specified Test Circuit.		27		ns
Total Gate Charge	Q_g	$V_{DS}=30V, V_{GS}=10V, I_D=5A$		15		nC
Gate-to-Source Charge	Q_{gs}	$V_{DS}=30V, V_{GS}=10V, I_D=5A$		2.4		nC
Gate-to-Drain "Miller" Charge	Q_{gd}	$V_{DS}=30V, V_{GS}=10V, I_D=5A$		3.2		nC
Diode Forward Voltage	V_{SD}	$I_S=5A, V_{GS}=0V$		0.81	1.2	V

Switching Time Test Circuit







Note on usage : Since the FW813 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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